## PRELIMINARY DATA SHEET

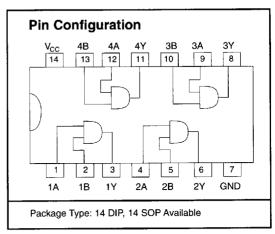
# GD74F08 QUAD 2-INPUT AND GATE

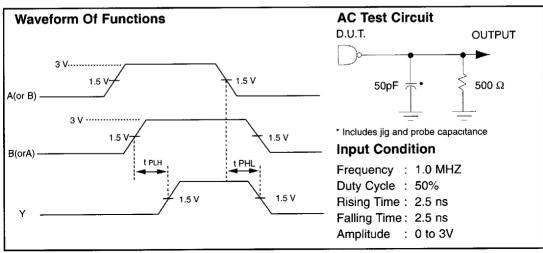
#### Description

This device contains four independent 2-input AND gates, each of which performs the Boolean functions  $Y = \overline{A} + \overline{B}$ .

#### Function Table (each gate)

Inputs		Outputs
Α	В	Υ
Н	Н	Н
L	Χ	L
Х	L	L
X Immater	ıal	





### **Absolute Maximum Ratings**

• Storage Temperature –65°C	to	150°C
◆ Ambient Temperature Under Bias		
◆ Juction Temperature Under Bias −0.5°C		
• V <sub>CC</sub> Voltage – 0.5 V		
◆ Input Voltage −5.0 V		
● Input Current		
● Output Voltage −0.5 V		

Note: Absolute Maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

#### **Recommended Operating Conditions**

SYMBOL	PARAMETER	MIN	MAX	UNIT
T <sub>A</sub>	Free Air Ambient Temperature	0	70	°C
V <sub>CC</sub>	Supply Voltage	4.5	5.5	V

#### **AC Characteristics**

SYMBOL	PARAMETER	TEST COI		
		TA = 25°C VCC = 5.0 V CL = 50 PF	TA = $0 \sim 70^{\circ}$ C VCC = $5V \pm 10\%$ CL = $50 \text{ PF}$	UNIT
		Min Typ Max	Min Typ Max	
tPLH	Propagation	3.0 4.2 5.6	3.0 - 6.6	ns
tPHL	Delay	2.5 4.0 5.3	2.5 - 6.3	ns

### DC Electrical Characteristics over recommended operating free-air temperature range

	1								
SYMBOL	PARAMETER	TEST CONDITIONS	Min	Тур	Max	UNIT	v <sub>cc</sub>	CIRCUIT	
v <sub>IH</sub>	Input High Voltage		2.0			٧			
V <sub>IL</sub>	Input Low Voltage				0.8	V			
V <sub>CD</sub>	Input Clamp Diode Voltage	I <sub>IN</sub> = -18mA			-1.2	V	Min	See FIG. 1	
V <sub>OH</sub>	Output High Voltage	I <sub>OH</sub> = -1mA I <sub>OH</sub> = -1mA	2.5 2.7			٧	4.5 4.75	See FIG. 2	
V <sub>OL</sub>	Output Low Voltage	I <sub>OL</sub> = 20mA			0.5	V	Min		
ΙΙ	Input High Current Breakdown Test	V <sub>IN</sub> = 7.0 V			7.0	μА	Max		
lіН	Input High Current	V <sub>IN</sub> = 2.7 V			5.0	μA	Max	See FIG. 3	
կլ	Input Low Current	V <sub>IN</sub> = 0.5 V			-0.6	mA	Max	1	
<sup>I</sup> ILK	Input Leakage Circuit Current	V <sub>IN</sub> = 4.75 V All other pins grounded			1.9	μА	0.0	See FIG. 4	
lolk	Output Leakage Circuit Current	V <sub>OUT</sub> = 150mV All other pins grounded			3.75	μА	0.0		
los	Output Short Circuit Current	V <sub>OUT</sub> = 0 V	-60		-150	mA	Max	See FIG. 5	
ICCH ICCL	Supply Current	V <sub>OUT</sub> = High V <sub>OUT</sub> = Low	-	5.5 8.6	8.3 12.9	mA	Max	See FIG. 6	

<sup>\*</sup> For IOS, Not more than one output should be shorted at a time, and duration should not exceed one second.

#### **DC Test Circuit**

FIG. 1  $V_{CD}$  Test (force  $I_{IN}$  and measure  $V_{CD}$ )

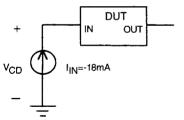


FIG. 2  $V_{OH}$  &  $V_{OL}$  Test (force I<sub>O</sub> and measure  $V_{OH}$  or  $V_{OL}$ )

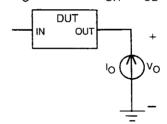
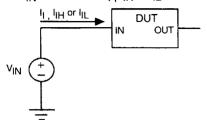


FIG. 3 I<sub>I</sub>, I<sub>IH</sub> & I<sub>IL</sub> Test (force  $V_{IN}$  and measure I<sub>I</sub> , I<sub>IH</sub> or I<sub>IL</sub>)



#### FIG. 5 IOS Test

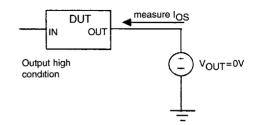
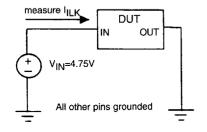


FIG. 4 IILK Test & IOLK Test



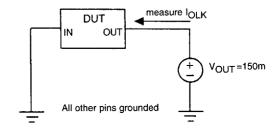


FIG. 6 I<sub>CCH</sub> Test & I<sub>CCL</sub> Test

